

0.5 A ultra low V_F MEGA Schottky barrier rectifier in leadless ultra small SOD882 package

Rev. 03 — 15 January 2010

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode with an integrated guard ring for stress protection encapsulated in a SOD882 leadless ultra small plastic package.

1.2 Features

- Forward current: 0.5 A
- Reverse voltage: 20 V
- Ultra low forward voltage
- Leadless ultra small plastic package
- Power dissipation comparable to SOT23

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Low power consumption applications

1.4 Quick reference data

| Table 1. | Quick reference data | | | |
|----------------|----------------------|-------|------|--|
| Symbol | Parameter | Value | Unit | |
| I _F | forward current | 0.5 | А | |
| V _R | reverse voltage | 20 | V | |



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2. Pinning information

| Table 2. | Discrete pinning | | |
|----------|------------------|-----------------------|-----------------|
| Pin | Description | Simplified outline | Symbol |
| 1 | cathode | [1] | |
| 2 | anode | 1 D 2 Bottom view | 1 🛃 2 sym001 |
| | | Top view 001aaa332 | |

[1] The marking bar indicates the cathode.

3. Ordering information

| Table 3. Ordering | g information | | |
|-------------------|---------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| PMEG2005AEL | - | leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm | SOD882 |

4. Marking

| Table 4. Marking | |
|------------------|--------------|
| Type number | Marking code |
| PMEG2005AEL | F2 |

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|--|--|----------------|------|------|
| V _R | continuous reverse voltage | | - | 20 | V |
| l _F | continuous forward current | | - | 0.5 | А |
| I _{FRM} | repetitive peak forward current | $t_p \leq 1 \text{ ms; } \delta \leq 0.25$ | - | 2.5 | А |
| I _{FSM} | non-repetitive peak forward current | t = 8 ms square wave | - | 3 | А |
| Tj | junction temperature | | <u>[1]</u> _ | 150 | °C |
| T _{amb} | operating ambient temperature | | <u>[1]</u> –65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

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[1] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating will be available on request.

6. Thermal characteristics

| Table 6. | Thermal characteristics | | | |
|----------------------|---|-------------|-------------------|------|
| Symbol | Parameter | Conditions | Value | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1][2]</u> 500 | K/W |

- [1] Refer to SOD882 standard mounting conditions (footprint), FR4 with 60 µm copper strip line.
- [2] For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

7. Characteristics

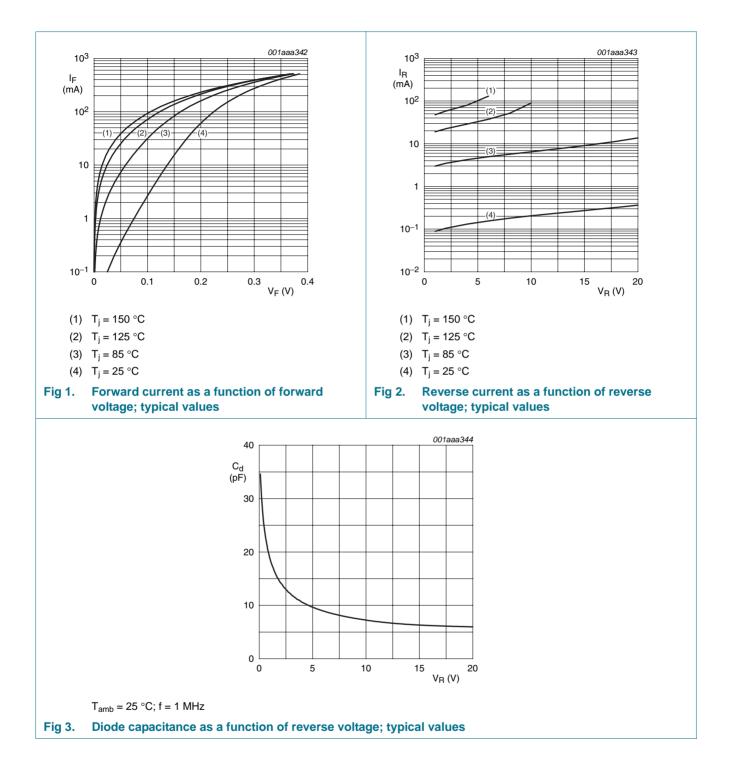
Table 7.Characteristics

 $T_{amb} = 25 \$ °C unless otherwise specified.

| Symbol | Parameter | Conditions | Тур | Max | Unit |
|----------------|--------------------|---|-----|------|------|
| V _F | continuous forward | see Figure 1; | | | |
| | voltage | I _F = 0.1 mA | 25 | 60 | mV |
| | | I _F = 1 mA | 75 | 110 | mV |
| | | I _F = 10 mA | 135 | 190 | mV |
| | | I _F = 100 mA | 220 | 290 | mV |
| | | I _F = 500 mA | 375 | 440 | mV |
| I _R | continuous reverse | see Figure 2; [1] | | | |
| | current | V _R = 10 V | 210 | 600 | μA |
| | | V _R = 20 V | 370 | 1500 | μA |
| C _d | diode capacitance | V _R = 1 V; f = 1 MHz; see <u>Figure 3</u> | 19 | 25 | pF |

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

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8. Package outline

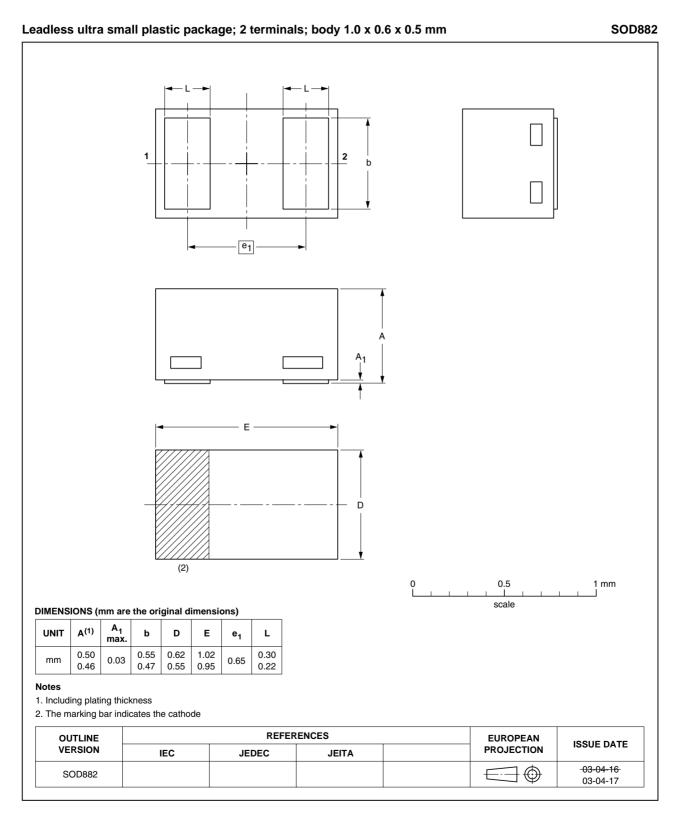


Fig 4. Package outline

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9. Revision history

| Table 8. Revision his | story | | | |
|-----------------------|--------------|--|---------------|---|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PMEG2005AEL_3 | 20100115 | Product data | - | PMEG2005AEL_2 |
| Modifications: | | eet was changed to reflect w legal definitions and disc | | e NXP Semiconductors, rere made to the technical |
| PMEG2005AEL_2 | 20040427 | Product data | - | PMEG2005AEL_1 |
| PMEG2005AEL_1 | 20040419 | Product data | - | - |

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10.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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